NSN 5961-01-509-1311

Transistor - Page 1 of 1

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View Online at https://aerobasegroup.com/nsn/5961-01-509-1311 **Inclosure Material:** Metal **Overall Length:** Between 1.328 inches and 1.358 inches **Overall Diameter:** 0.875 inches **End Application:** C-17a aircraft **Mounting Facility Quantity: Mounting Method:** Terminal and unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 170.0 collector to base voltage/static/emitter open and 150.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 16.00 amperes source cutoff current and 30.00 amperes zero-gate-voltage source current blank and 4.00 amperes source cutoff current and 15.00 amperes zero-gate-voltage source current of standard range **Power Rating Per Characteristic:** 250.0 watts small-signal input power, common-emitter outside diameter **Product Name:** Transistor, silicon, n-p-n, high current **Terminal Type And Quantity:** 2 pin and 2 unthreaded hole Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: